

ISSN: 0973-3469, Vol.19, No.(3) 2022, Pg.170-176

Material Science Research India

www.materialsciencejournal.org

Analytical Study of Nanomaterials under High Pressure

ROHIT GUPTA^{1*} and MOHIT GUPTA²

¹Department of Physics, Agra College, Dr. Bhimrao Ambedkar University, Agra, India. ²Department of Chemistry, Institute of Basic Science, Dr. Bhimrao Ambedkar University, Khandari Campus, Agra, India.

Abstract

Our previous study we extended an equation of state model for second order bulk modulus from recent predicted model and calculated variation of pressure with volume for several nanomaterials. Now we use such a model for few other nanomaterials like, TiO_2 (anatase), Ni (20 nm), CdSe (rock salt phase), AIN (Hexagonal), 3C-SiC (30 nm) and Rb₃ C₆₀., compare with some other equation of state for nanomaterials and experimental data. The Microsoft Office software has been used to do the calculations. The studies gives great agreement with other EOS and experimental data. The study must be useful at high pressure when the experimental data are not available. So the given study must we useful at high pressure.



Article History

Received: 29 September 2022 Accepted: 07 November 2022

Keywords

Bulk Modulus; Equation of State; High Pressure; Nanomaterials; Solid.

Introduction

Recently the study of nanomaterials are achieving more attention due to its surprising properties such as size, shape, morphology, compressible properties, and their structural properties changed with pressure, volume, and temperature.^{1,2} So its extraordinary properties mechanical, thermal and electronic properties make it more relievable for developing several multi functional applications.³ Synthesized and electro chemicalanodizations experimental were studied under high pressure up to 31 GPa for Anatase titanium dioxide (TiO₂) nanotubes by Raman spectroscopy and synchrotron X-ray diffraction⁴ and study of a synchrotron X-ray diffraction presented pressure-induced changes innanocrystalline anatase (30-40 nm) to 35 GPa.⁵

A simple theory predicts for several nanomaterials on the effect of pressure for volume expansion⁶ and high-pressure behavior of Ni-filled and Fe-filled MWCNTs examined up to 27 GPa and 19 GPa with help of synchrotron-based angle-

CONTACT Rohit Gupta rohitguptaagraindia@gmail.com Operatment of Physics, Agra College, Dr. Bhimrao Ambedkar University, Agra, India.



© 2022 The Author(s). Published by Enviro Research Publishers.

This is an **∂** Open Access article licensed under a Creative Commons license: Attribution 4.0 International (CC-BY). Doi: http://dx.doi.org/10.13005/msri/190308

dispersive X-ray diffraction.⁷ A equation of state studied for several namomaterials such as metals Ni (20 nm), α -Fe (nanotubes), Cu (80 nm) and Ag (55nm), semiconductors Ge (49 nm), Si, CdSe (rock-salt phase), MgO (20 nm) and ZnO, and carbon nanotube (CNT) in term pressure related with volume and their theoretical data agreement between experimental data.⁸ Plasma Enhanced Chemical Vapor Deposition (PECVD) and annealing technique are used in Crystal size synthesized of nanocrystal 3C-SiC (than 30 nm).⁹ H.A. Ludwig , investigated X-ray experiments under high pressure up to 6 GPa at 300°Kfor Rb3C60using a diamond anvil cell and angular dispersive X-ray scattering.¹⁰

Method of Analysis

These equations of state (EOS) are determining the effect of pressure on nanomaterials, where P is a function of relative change in Volume (V/V₀) as several equations of states (EOS) written as follows: Rohit Gupta EOS written as, ¹¹

Rohit Gupta EOS written as,11

$$P = B_0 \left(1 - \frac{v}{v_0} \right) + B_0 \left\{ \frac{(B_0'+1)}{2} \right\} \left(1 - \frac{v}{v_0} \right)^2 + B_0 \left\{ \frac{(B_0 B_0''+3B_0'+2)}{6} \right\} \left(1 - \frac{v}{v_0} \right)^3 \dots (1)$$

Mie-Gruneisen EOS written as,12

$$P = B_0 \left(1 - \frac{v}{v_0} \right) + \frac{B_0 (B_0' + 1)}{2} \left(1 - \frac{v}{v_0} \right)^2 \qquad \dots (2)$$

Tait EOS written as,13

$$P = \frac{B_0}{(B_0'+1)} \left[exp\left\{ \left(B_0'+1 \right) \left(1 - \frac{v}{v_0} \right) \right\} - 1 \right] \qquad \dots (3)$$

Murnaghan EOS written as,14

$$P = \frac{B_0}{B_0'} \left[\exp\left\{ -B_0' \ln \frac{V}{V_0} \right\} - 1 \right] \qquad \dots (4)$$

Birch–Murnaghan EOS written as,15

$$P = \frac{3}{2} B_0 \left\{ \left(\frac{v}{v_0} \right)^{7/3} - \left(\frac{v}{v_0} \right)^{5/3} \right\} \times \left[1 + \frac{3}{4} \left(B_0' - 4 \right) \left\{ \left(\frac{v}{v_0} \right)^{2/3} - 1 \right\} \right] \quad \dots (5)$$

Vinet EOS written as,16

$$P = 3B_0 \left(\frac{V}{V_0}\right)^{-2/3} \left[1 - \left(\frac{V}{V_0}\right)^{1/3}\right]$$

× $exp\left[\frac{3(B_0'-1)}{2} \left\{1 - \left(\frac{V}{V_0}\right)^{1/3}\right\}\right] ...(6)$

Kholiya and Chandra EOS written as,17

$$P = \frac{B_0}{2} \left[(B'_0 - 3) - 2(B'_0 - 2) \left(\frac{v}{v_0}\right)^{-1} + (B'_0 - 1) \left(\frac{v}{v_0}\right)^{-2} \right] \dots (7)$$

Kalita and Mariotto *et al.*²⁴ examined experimental data for several nanomaterial compounds but here our interest only few material such as, TiO₂ (anatase), Ni (20 nm), CdSe (rock salt phase), AlN (Hexagonal), 3C-SiC (30 nm) and Rb₃C₆₀. The given experimental data is compared with several other EOSs such as, Rohit Gupta EOS, Mie–Gruneisen EOS, Tait EOS, Murnaghan EOS, Birch–Murnaghan EOS, Vinet EOSandKholiya-Chandra EOS. Kholiya and Chandra¹⁷ recently performed computational study on high-pressure compression behaviour of nanomaterials and provided good agreement with experimental data at high pressure also verified by average deviations.

S. No.	Nanomaterial	B₀ (GPa)	B' ₀	в",	Max Pressure (GPa)	Reference
1	TiO ₂ (anatase)	190.4	4	0.470	16.72	[18]
2	Ni (20 nm)	185	4	0.122	33.40	[19]
3	CdSe (rock salt phase)	74	4	0.360	8.00	[20]
4	AIN (Hexagonal)	321	4	0.481	14.5	[21]
5	3C-SiC (30 nm)	245	2.9	0.128	23	[22]
6	Rb ₃ C ₆₀	17.35	3.9	0.277	0.66	[23]

Table 1 Shows values of B₀, B'₀, and B"₀ and average percentage deviations from Eq. (1).

Results and Discussions

Second order bulk modulus (B"₀)are calculated for TiO₂ (anatase), Ni (20 nm), CdSe (rock salt phase), AIN (Hexagonal), 3C-SiC (30 nm) and $Rb_{3}C_{60}$ nanomaterials and finding pressure for various points with respect to volume for several nanomaterialequation of states like, Rohit Gupta EOS, Mie-Gruneisen EOS, Tait EOS, Murnaghan EOS, Birch-Murnaghan EOS Vinet EOS and Kholiya-Chandra EOS. The data for all nanomaterials defined from three constants such as Bo, Bo' and Bo" are listed in table 1. The second order bulk modulus Bo" are calculated from equation (1). Under compressions of such nanomaterials (TiO₂ (anatase), Ni (20 nm), CdSe (rock salt phase), AIN (Hexagonal), 3C-SiC (30 nm) and $Rb_{3}C_{60}$) pressures and its validity test arecalculated againfrom Eq. (1) and several other isothermal EOSs Eq. (2 to 7). Microsoft Office software has been used to do the calculations.

The results obtained from these EOSs are presented in Fig. 1 to 6 in terms between pressure and (V/V_{o}) and its experimental data from.18-23 Eq. (1) gives better agreement such as compared with the other EOSs. The obtained results compared with experimental data show in Figs. 1 to 6, thesevalues calculated from using Eq. (1) and closer to experimental data of nanomaterials. The experimental uncertainty result provided by Sharma and Kumar² with experimental measured P-V data is often pressuring calibration errors, therefore, we considered Eq. (1) calculation for the compression behavior of TiO₂ (anatase), Ni (20 nm), CdSe (rock salt phase), AIN (Hexagonal), 3C-SiC (30 nm) and $Rb_{3}C_{60}$. The results are reported in Fig. 1 to 6 along with the experimental data¹⁸⁻²³ and these corresponding results are presented in Table 1. Significantly, the results are showing better agreement with the experimental data.



Fig. 1: Several EOSs are used for calculating high-pressure behaviour V/V₀ for TiO, (Anatase).



Fig. 2: Several EOSs are used for calculating high-pressure behaviour V/V₀ for Ni (20 nm).



Fig. 3: Several EOSs are used for calculating high-pressure behaviour V/Vo for CDSE (Rock Salt).



Fig. 4: Several EOSs are used for calculating high-pressure behaviour V/Vo for AIN (Hexagonal).



Fig. 5: Several EOSs are used for calculating high-pressure behaviour V/V₀ for 3C-SiC (30 nm).



Fig. 6: Several EOSs are used for calculating high-pressure behaviour V/Vo for Rb₃C₆₀.

Conclusion

Second order pressure derivative of bulk modulus EOS for nanomaterialsare predicted by our previous EOS study. EOSs for nanomaterials aremuch useful under high pressure compression behavior of nanomaterials and solids. The major advantages of these EOSs are that the experimental data is not available. Therefore the given studies for nanomaterials must be helpful under highpressure compression behavior because at this level arrangement of experimental setup don't easy task. The results give better deal compare with experimental data and EOSs data, it is clear from figure 1 to 6. Present work is simple and effective method to study compression behaviour of nanomaterials and solids.

Acknowledgement

The author would like to thank, (Insert university name and Dept. name) for their guidance and support to complete this article.

Funding

The author(s) received no financial support for the research, authorship, and/or publication of this article.

Conflicts of Interest

The authors declare no competing interests.

References

- Ye C, Pan S S, Teng X M and Li G H, J.Appl. Phys. 102, 1 (2007).
- Sharma U D and Kumar M, *Physica* B 405, 2820 (2010).
- 3. Kumar R, Sharma U D, Kumar M, *Modern Physics Letters* B 24, 2647 (2010).
- Dong Z, Xiao F, Zhao A, Liu L, Sham T, Song Y, RSC Adv. 6, 76142 (2016).
- 5. Swamy V, Dubrovinsky L S, Dubrovinskaia N

A, Simionovici A S, Drakopoulos M, Dmitriev V, Weber H P, *Solid State Commun.* 125, 111 (2003).

- 6. Gleiter H 2000 Acta Materialia 48 6243.
- Poswal H K, Karmaker S, Tyagi P K, Mishra D S, Busetto E, Sharma S M, Sood A K, *Phys. Stat. Sol.* (b) 244, 3612 (2007).
- Singh M,Tlali S, Narayan H, Nanoscience and Nanotechnology 2, 201 (2012).

- 9. Ye C, Ran G,Zhou W, Qu Y, Yan X, Cheng Q, Li N, Nanomaterials 7, 408 (2017).
- Ludwig H A, Fietz W H, Hornung F W, Grube K, Renker B, Burkhart G J, *Physica C* Superconductivity 234, 45 (1994).
- 11. Gupta R, Gupta *M, Bull. Mater. Sci.* 44, 218 (2021).
- Born M, Huang K, In Dynamical Theory of Crystals Lattice. Oxford University Press, Oxford(1995).
- Wang Z, Tait K, Zhao Y, Schiferl D, Zha C, Uchida H, Downs R T, *J. Phys. Chem.* B108, 11506 (2004).
- Anderson O L, In Equation of State for Geophysics and Ceramic Sciences. Oxford University Press, Oxford(1995).
- 15. Birch F, J. Geophys. Res. 57, 227 (1952).
- 16. Vinet P, Ferrente J, Smith J R, Rose J H, *J. Phys C: Solid State* Phys.19, 467 (1986).

- 17. Kholiya K and Chandra J, J. *Taibah Univ. Sci.* 8, 137 (2014).
- Swamy V, Dubrovinsky L S, Dubrovinskaia N A, Simionovici A S, Drakopoulos M, Dmitriev V, Weber H P, *Solid State Commun.* 125, 111 (2003).
- 19. Chen B, Penwell D, Kruger M B, *Solid State Commun.* 115, 191 (2000).
- 20. Tolbert S H, Alivisatos A P, *J. Chem. Phys.* 102, 1 (1995).
- 21. Wang Z, Tait K, Zhao Y, Schifer D, *J. Phys. Chem.* B 108, 11506 (2004).
- 22. Liu H, Jin C, Chen J, Hu J, *J. Am. Ceram.* Soc. 87, 2291 (2004).
- Zhou O, Vaughan G B M, Zhu Q, Fischer J E, Heiner P A, Coustel N, Mc Cauley J P J, Smith *A B,Science* 255, 833 (1992).
- 24. Kalita K E L, Mariotto G, Kalita P E, Ohki Y, *Physica B* 365, 155 (2005).